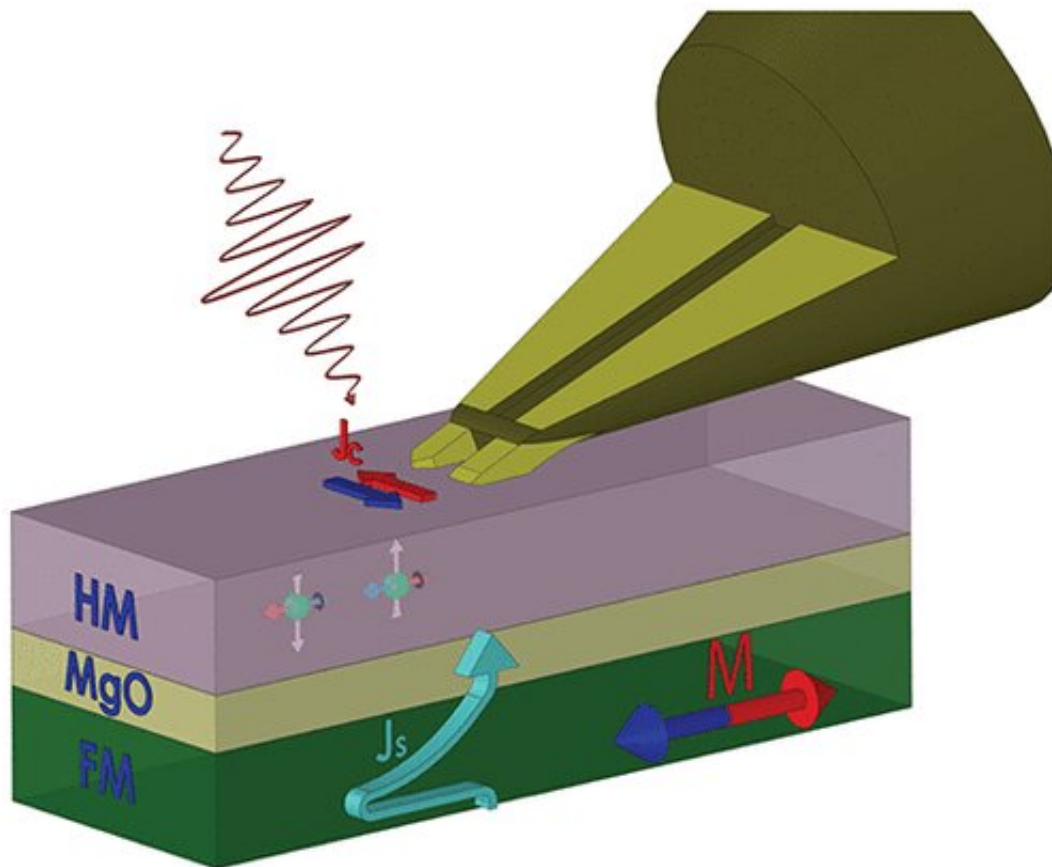


# Spintronics: How an atom-thin insulator helps transport spins

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Graphical abstract. Credit: *Nano Letters* (2022). DOI: 10.1021/acs.nanolett.1c04358

An intermediate layer consisting of a few atoms is helping to improve the transport of spin currents from one material to another. Until now,

this process involves significant losses. A team from Martin Luther University Halle-Wittenberg (MLU), the Max Planck Institute (MPI) for Microstructure Physics, and the Freie Universität Berlin reports in the ACS scientific journal *Nano Letters* on how this can be avoided. The researchers thus demonstrate important new insights relevant for many spintronic applications, including energy-efficient and ultra-fast storage technologies of the future.

In modern microelectronics, the charge of electrons is used to carry information in [electronic components](#), mobile phones and storage media. The [charge transport](#) requires a relatively large amount of energy and generates heat. Spintronics could offer an energy-saving alternative. The basic idea is to utilize spin in information processing. Spin is the intrinsic angular momentum of the electrons that creates a magnetic moment. This generates the magnetism that will ultimately be used to process information.

In spintronics, spin currents also have to be transferred from one material to the next. "In many cases, the spin transport across interfaces is a very lossy process," explains physicist Professor Georg Woltersdorf from MLU, who led the study. The team looked for a way to mitigate these losses by using an approach that, at first, sounds rather contradictory: they integrated an insulating barrier between the two materials.

"We designed the insulator at the [atomic level](#) so that it turned metallic and could conduct the spin currents. This enabled us to significantly improve the spin transport and optimize the interfacial properties," says Woltersdorf, summing up the process. The material samples were produced at the Max Planck Institute for Microstructure Physics. The unexpected effect was discovered through measurements of spin transport conducted at MLU and the Freie Universität Berlin. The team also provides the theoretical basis for the new discovery. According to

Woltersdorf, this can be described using relatively simple models without [spin-orbit coupling](#).

The results are highly relevant for many spintronic applications. For example, they can be used to improve spintronic terahertz emitters. Terahertz radiation is not not only applied in research, but also in high-frequency electronics, medicine, materials testing and communication technology.

**More information:** Mohamed Amine Wahada et al, Atomic Scale Control of Spin Current Transmission at Interfaces, *Nano Letters* (2022). [DOI: 10.1021/acs.nanolett.1c04358](https://doi.org/10.1021/acs.nanolett.1c04358)

Provided by Martin Luther University Halle-Wittenberg

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